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60V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN E-LINE

SUMMARY

 BV_{CEO} = -60V : R_{SAT} = 38m Ω ; I_{C} = -3.5A

DESCRIPTION

Packaged in the E-line outline this new low saturation 60V PNP transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.

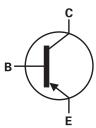
E-line

FEATURES

- 3.5 amps continuous current
- Up to 15 amps peak current
- Very low saturation voltages
- Excellent gain up to 10 amps

APPLICATIONS

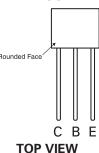
- DC DC converters
- MOSFET gate drivers
- Power switches
- Motor control



ORDERING INFORMATION

DEVICE	QUANTITY PER REEL		
ZXTP2012ASTOA	2,000 units / reel		
ZXTP2012ASTZ	2,000 units / carton		

PINOUT



DEVICE MARKING

ZXT P20



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-base voltage	BV _{CBO}	-100	V
Collector-emitter voltage	BV _{CEO}	-60	V
Emitter-base voltage	BV _{EBO}	-7	V
Continuous collector current (a)	Ic	-3.5	А
Peak pulse current	I _{CM}	-15	А
Practical power dissipation at T _A =25°C ^(a)	P _D	1.0	W
Linear derating factor		8	mW/°C
Power dissipation at T _A =25°C ^(b)	P _D	0.71	W
Linear derating factor		5.7	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to ambient ^(a)	$R_{\Theta JA}$	125	°C/W
Junction to ambient ^(b)	$R_{\Theta JA}$	175	°C/W

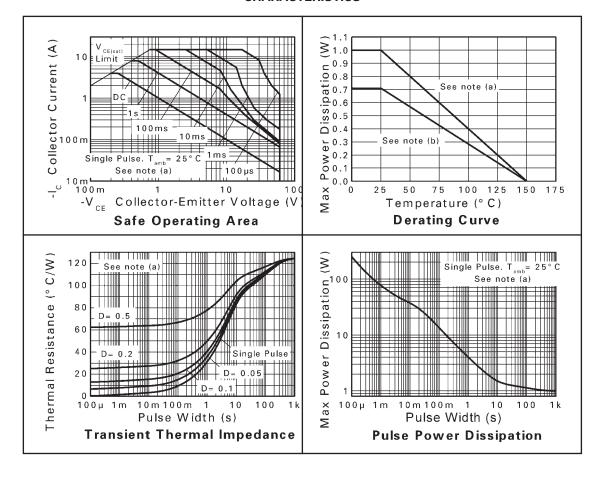
NOTES

(b) For a device mounted in a socket in still air conditions. Collector lead length 10mm.



⁽a) For a device through hole mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions. Collector lead length to solder point 4mm.

CHARACTERISTICS





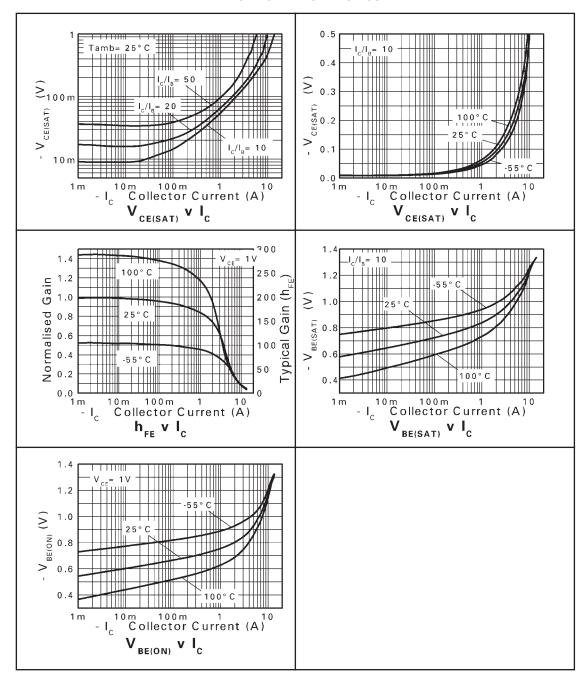
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25$ °C unless otherwise stated)

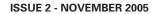
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-base breakdown voltage	BV _{CBO}	-100	-120		V	I _C =-100μA
Collector-emitter breakdown voltage	BV _{CER}	-100	-120		V	I _C =-1μA, RB≤1kΩ
Collector-emitter breakdown voltage	BV _{CEO}	-60	-80		V	I _C =-10mA*
Emitter-base breakdown voltage	BV _{EBO}	-7	-8.1		V	I _E =-100μA
Collector cut-off current	I _{CBO}		<1	-20	nA	V _{CB} =-80V
				-0.5	μΑ	V _{CB} =-80V, T _{amb} =100°C
Collector cut-off current	I _{CER}		<1	-20	nA	V _{CB} =-80V
	R≤1kΩ			-0.5	μΑ	V _{CB} =-80V, T _{amb} =100°C
Emitter cut-off current	I _{EBO}		<1	-10	nA	V _{EB} =-6V
Collector-emitter saturation voltage	V _{CE(SAT)}		-14	-20	mV	I _C =-0.1A, I _B =-10mA*
			-50	-65	mV	I _C =-1A, I _B =-100mA*
			-80	-115	mV	I _C =-2A, I _B =-200mA*
			-145	-210	mV	I _C =-4A, I _B =-400mA*
Base-emitter saturation voltage	V _{BE(SAT)}		-960	-1060	mV	I _C =-4A, I _B =-400mA*
Base-emitter turn-on voltage	V _{BE(ON)}		-850	-960	mV	I _C =-4A, V _{CE} =-1V*
Static forward current transfer ratio	h _{FE}	100	250			I _C =-10mA, V _{CE} =-1V*
		100	200	300		I _C =-1A, V _{CE} =-1V*
		65	120			I _C =-4A, V _{CE} =-1V*
		10	25			I _C =-10A, V _{CE} =-1V*
Transition frequency	f _T		120		MHz	I _C =-100mA, V _{CE} =-10V
						f=50MHz
Output capacitance	C _{OBO}		48		рF	V _{CB} =-10V, f=1MHz*
Switching times	t _{ON}		39		ns	I _C =-1A, V _{CC} =-10V,
	t _{OFF}		370			I _{B1} =I _{B2} =-100mA

^{*} Measured under pulsed conditions. Pulse width $\leq 300 \mu s$; duty cycle $\leq 2\%$.



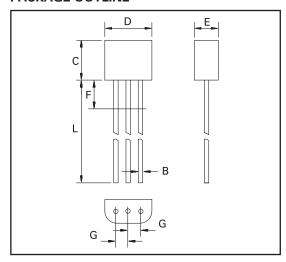
TYPICAL CHARACTERISTICS







PACKAGE OUTLINE



Controlling dimensions are in millimeters. Approximate conversions are given in inches

PACKAGE DIMENSIONS

DIM	DIM Millimeters Min Max		Inches	
DIIVI			Min	Max
А	0.41	0.495	0.016	0.0195
В	0.41	0.495	0.016	0.0195
С	3.61	4.01	0.142	0.158
D	4.37	4.77	0.172	0.188
Е	2.16	2.41	0.085	0.095
F	_	2.50	_	0.098
G	1.27	NOM	0.050	NOM
L	13.00	13.97	0.512	0.550

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